MSG43004

SiGe HBT type

For low-noise RF amplifier

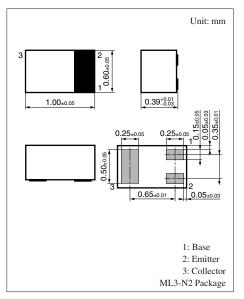
■ Features

- Compatible between high breakdown voltage and high cut-off frequency
- Low noise, high-gain amplification
- Optimal size reduction and high level integration for ultra-small packages

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	9	V	
Collector-emitter voltage (Base open)	V _{CEO}	6	V	
Emitter-base voltage (Collector open)	V_{EBO}	1	V	
Collector current	I_C	100	mA	
Collector power dissipation *	P _C	100	mW	
Junction temperature	T_j	125	°C	
Storage temperature	T _{stg}	-55 to +125	°C	

Note) *: Copper plate at the collector is 5.0 mm 2 on substrate at 10 mm \times 12 mm \times 0.8 mm.



Marking Symbol: 5Y

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

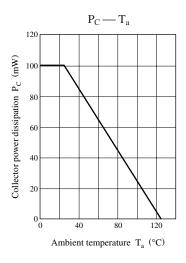
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 9 \text{ V}, I_{E} = 0$			1	μΑ
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 6 \text{ V}, I_{B} = 0$			1	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 1 \text{ V}, I_C = 0$			1	μΑ
Forward current transfer ratio	h _{FE}	$V_{CE} = 3 \text{ V}, I_{C} = 15 \text{ mA}$	100		220	_
Transition frequency *	f_T	$V_{CE} = 3 \text{ V}, I_{C} = 30 \text{ mA}, f = 2 \text{ GHz}$		17		GHz
Forward transfer gain *	S _{21e} 2	$V_{CE} = 3 \text{ V}, I_{C} = 30 \text{ mA}, f = 2 \text{ GHz}$	6.0	9.0		dB
Noise figure *	NF	$V_{CE} = 3 \text{ V}, I_{C} = 15 \text{ mA}, f = 2 \text{ GHz}$		1.4	2.0	dB
Collector output capacitance	C _{ob}	$V_{CB} = 3 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		0.6	0.9	pF
(Common base, input open circuited) *						

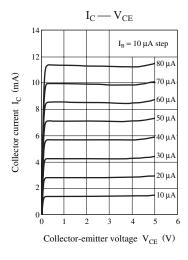
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

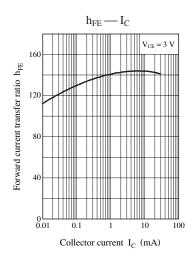
- 2. Observe precautions for handling. Electrostatic sensitive devices.
- 3. *: Verified by random sampling

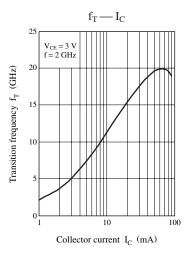
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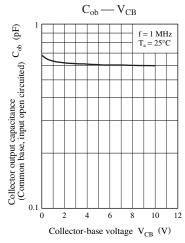
Panasonic

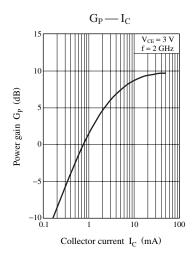


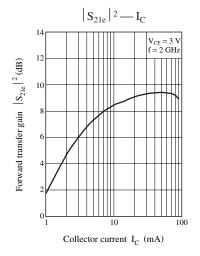


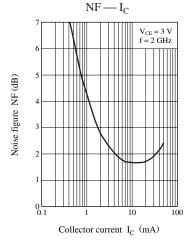


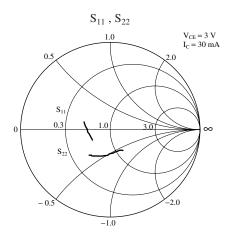




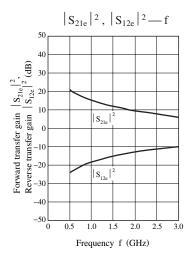








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